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| <b>Search Notes</b><br><br> | <b>Application/Control No.</b><br><br>10582993 | <b>Applicant(s)/Patent Under Reexamination</b><br><br>KRAEMER, WILHELM |
|  | <b>Examiner</b><br><br>JOHN W POOS             | <b>Art Unit</b><br><br>2816  |

| SEARCHED |          |           |          |
|----------|----------|-----------|----------|
| Class    | Subclass | Date      | Examiner |
| 327      | 306, 308 | 12/6/2007 | JP       |
| 327      | 435      | 12/5/2007 | JP       |
| 333      | 81r, 103 | 7/2/2008  | JP       |
| 327      | 308      | 7/2/2008  | JP       |

| SEARCH NOTES   |           |          |
|--|-----------|----------|
| Search Notes   | Date      | Examiner |
| inventor search in eDAN and EAST                                 | 12/5/2007 | JP       |
| terms: attenuator, MOS, MOSFET, FET, high frequency              | 12/6/2007 | JP       |
| Update Search see attached EAST search history                   | 4/25/2008 | JP       |
| backward and forward citation search on all pertinent references | 7/2/2008  | JP       |

| INTERFERENCE SEARCH |          |      |          |
|---------------------|----------|------|----------|
| Class               | Subclass | Date | Examiner |
|                     |          |      |          |